



*The Infinite Bandwidth Company™*

## MIC4426/4427/4428

### Dual 1.5A-Peak Low-Side MOSFET Driver

#### Final Information

### General Description

The MIC4426/4427/4428 family are highly-reliable dual low-side MOSFET drivers fabricated on a BiCMOS/DMOS process for low power consumption and high efficiency. These drivers translate TTL or CMOS input logic levels to output voltage levels that swing within 25mV of the positive supply or ground. Comparable bipolar devices are capable of swinging only to within 1V of the supply. The MIC4426/7/8 is available in three configurations: dual inverting, dual noninverting, and one inverting plus one noninverting output.

The MIC4426/4427/4428 are pin-compatible replacements for the MIC426/427/428 and MIC1426/1427/1428 with improved electrical performance and rugged design (Refer to the Device Replacement lists on the following page). They can withstand up to 500mA of reverse current (either polarity) without latching and up to 5V noise spikes (either polarity) on ground pins.

Primarily intended for driving power MOSFETs, MIC4426/7/8 drivers are suitable for driving other loads (capacitive, resistive, or inductive) which require low-impedance, high peak current, and fast switching time. Other applications include driving heavily loaded clock lines, coaxial cables, or piezoelectric transducers. The only load limitation is that total driver power dissipation must not exceed the limits of the package.

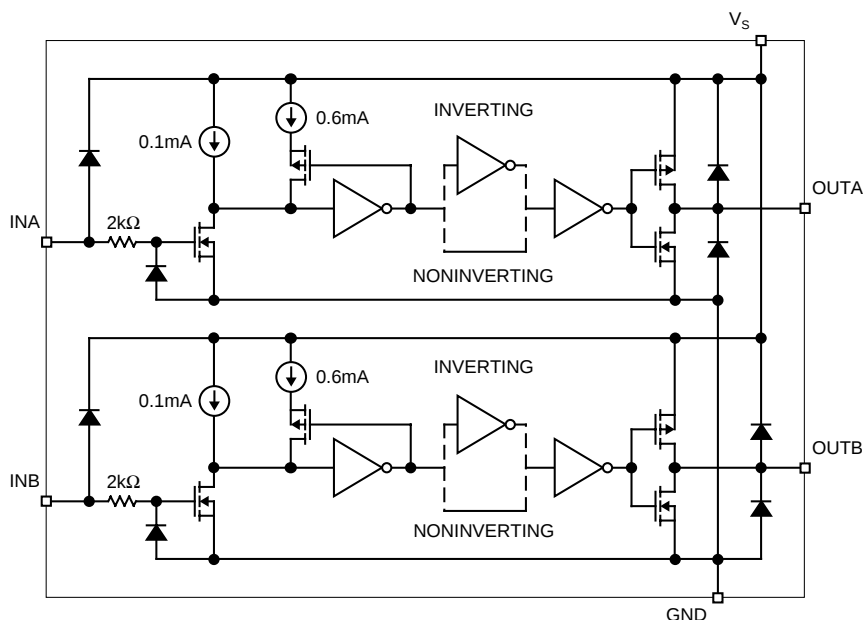
### Features

- Bipolar/CMOS/DMOS construction
- Latch-up protection to >500mA reverse current
- 1.5A-peak output current
- 4.5V to 18V operating range
- Low quiescent supply current
  - 4mA at logic 1 input
  - 400µA at logic 0 input
- Switches 1000pF in 25ns
- Matched rise and fall times
- 7Ω output impedance
- < 40ns typical delay
- Logic-input threshold independent of supply voltage
- Logic-input protection to -5V
- 6pF typical equivalent input capacitance
- 25mV max. output offset from supply or ground
- Replaces MIC426/427/428 and MIC1426/1427/1428
- Dual inverting, dual noninverting, and inverting/noninverting configurations
- ESD protection

### Applications

- MOSFET driver
- Clock line driver
- Coax cable driver
- Piezoelectric transducer driver

### Functional Diagram



## Ordering Information

| Part Number | Temperature Range | Package            | Configuration            |
|-------------|-------------------|--------------------|--------------------------|
| MIC4426AM   | –55°C to +125°C   | 8-lead SOIC        | Dual Inverting           |
| MIC4426BM   | –40°C to +85°C    | 8-lead SOIC        | Dual Inverting           |
| MIC4426BMM  | –40°C to +85°C    | 8-lead MSOP        | Dual Inverting           |
| MIC4426BN   | –40°C to +85°C    | 8-lead Plastic DIP | Dual Inverting           |
| MIC4427AM   | –55°C to +125°C   | 8-lead SOIC        | Dual Noninverting        |
| MIC4427BM   | –40°C to +85°C    | 8-lead SOIC        | Dual Noninverting        |
| MIC4427BMM  | –40°C to +85°C    | 8-lead MSOP        | Dual Noninverting        |
| MIC4427BN   | –40°C to +85°C    | 8-pin Plastic DIP  | Dual Noninverting        |
| MIC4428AM   | –55°C to +125°C   | 8-lead SOIC        | Inverting + Noninverting |
| MIC4428BM   | –40°C to +85°C    | 8-lead SOIC        | Inverting + Noninverting |
| MIC4428BMM  | –40°C to +85°C    | 8-lead MSOP        | Inverting + Noninverting |
| MIC4428BN   | –40°C to +85°C    | 8-lead Plastic DIP | Inverting + Noninverting |

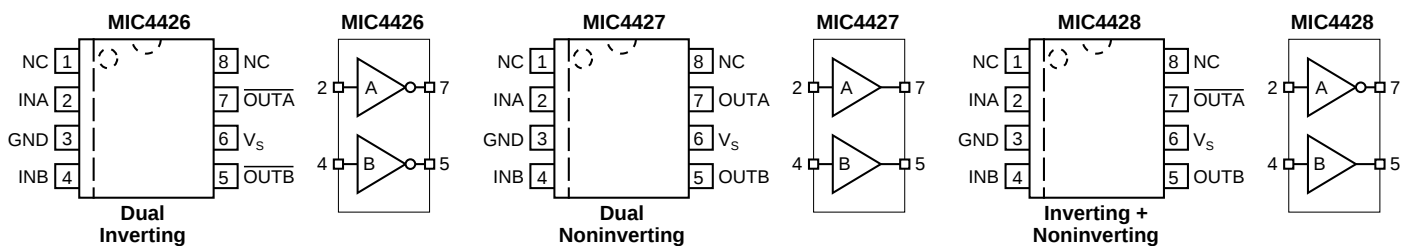
### MIC426/427/428 Device Replacement

| Discontinued Number | Replacement |
|---------------------|-------------|
| MIC426CM            | MIC4426BM   |
| MIC426BM            | MIC4426BM   |
| MIC426CN            | MIC4426BN   |
| MIC426BN            | MIC4426BN   |
| MIC427CM            | MIC4427BM   |
| MIC427BM            | MIC4427BM   |
| MIC427CN            | MIC4427BN   |
| MIC427BN            | MIC4427BN   |
| MIC428CM            | MIC4428BM   |
| MIC428BM            | MIC4428BM   |
| MIC428CN            | MIC4428BN   |
| MIC428BN            | MIC4428BN   |

### MIC1426/1427/1428 Device Replacement

| Discontinued Number | Replacement |
|---------------------|-------------|
| MIC1426CM           | MIC4426BM   |
| MIC1426BM           | MIC4426BM   |
| MIC1426CN           | MIC4426BN   |
| MIC1426BN           | MIC4426BN   |
| MIC1427CM           | MIC4427BM   |
| MIC1427BM           | MIC4427BM   |
| MIC1427CN           | MIC4427BN   |
| MIC1427BN           | MIC4427BN   |
| MIC1428CM           | MIC4428BM   |
| MIC1428BM           | MIC4428BM   |
| MIC1428CN           | MIC4428BN   |
| MIC1428BN           | MIC4428BN   |

## Pin Configuration



## Pin Description

| Pin Number | Pin Name       | Pin Function                                      |
|------------|----------------|---------------------------------------------------|
| 1, 8       | NC             | not internally connected                          |
| 2          | INA            | Control Input A: TTL/CMOS compatible logic input. |
| 3          | GND            | Ground                                            |
| 4          | INB            | Control Input B: TTL/CMOS compatible logic input. |
| 5          | OUTB           | Output B: CMOS totem-pole output.                 |
| 6          | V <sub>S</sub> | Supply Input: +4.5V to +18V                       |
| 7          | OUTA           | Output A: CMOS totem-pole output.                 |

**Absolute Maximum Ratings (Note 1)**

|                                |                          |
|--------------------------------|--------------------------|
| Supply Voltage ( $V_S$ )       | +22V                     |
| Input Voltage ( $V_{IN}$ )     | $V_S + 0.3V$ to GND – 5V |
| Junction Temperature ( $T_J$ ) | 150°C                    |
| Storage Temperature            | –65°C to +150°C          |
| Lead Temperature (10 sec.)     | 300°C                    |
| ESD Rating, <b>Note 3</b>      |                          |

**Operating Ratings (Note 2)**

|                             |                 |
|-----------------------------|-----------------|
| Supply Voltage ( $V_S$ )    | +4.5V to +18V   |
| Temperature Range ( $T_A$ ) |                 |
| (A)                         | –55°C to +125°C |
| (B)                         | –40°C to +85°C  |
| Package Thermal Resistance  |                 |
| PDIP $\theta_{JA}$          | 130°C/W         |
| PDIP $\theta_{JC}$          | 42°C/W          |
| SOIC $\theta_{JA}$          | 120°C/W         |
| SOIC $\theta_{JC}$          | 75°C/W          |
| MSOP $\theta_{JC}$          | 250°C/W         |

**Electrical Characteristics**

4.5V  $\leq V_S \leq$  18V;  $T_A = 25^\circ\text{C}$ , **bold** values indicate full specified temperature range; unless noted.

| Symbol                | Parameter             | Condition                                    | Min               | Typ                 | Max               | Units                |
|-----------------------|-----------------------|----------------------------------------------|-------------------|---------------------|-------------------|----------------------|
| <b>Input</b>          |                       |                                              |                   |                     |                   |                      |
| $V_{IH}$              | Logic 1 Input Voltage |                                              | 2.4<br><b>2.4</b> | 1.4<br><b>1.5</b>   |                   | V<br>V               |
| $V_{IL}$              | Logic 0 Input Voltage |                                              |                   | 1.1<br><b>1.0</b>   | 0.8<br><b>0.8</b> | V<br>V               |
| $I_{IN}$              | Input Current         | $0 \leq V_{IN} \leq V_S$                     | <b>–1</b>         |                     | <b>1</b>          | $\mu\text{A}$        |
| <b>Output</b>         |                       |                                              |                   |                     |                   |                      |
| $V_{OH}$              | High Output Voltage   |                                              | $V_S - 0.025$     |                     |                   | V                    |
| $V_{OL}$              | Low Output Voltage    |                                              |                   |                     | <b>0.025</b>      | V                    |
| $R_O$                 | Output Resistance     | $I_{OUT} = 10\text{mA}$ , $V_S = 18\text{V}$ |                   | 6<br><b>8</b>       | 10<br><b>12</b>   | $\Omega$<br>$\Omega$ |
| $I_{PK}$              | Peak Output Current   |                                              |                   | <b>1.5</b>          |                   | A                    |
| I                     | Latch-Up Protection   | withstand reverse current                    | <b>&gt;500</b>    |                     |                   | mA                   |
| <b>Switching Time</b> |                       |                                              |                   |                     |                   |                      |
| $t_R$                 | Rise Time             | test Figure 1                                |                   | 18<br><b>20</b>     | 30<br><b>40</b>   | ns<br>ns             |
| $t_F$                 | Fall Time             | test Figure 1                                |                   | 15<br><b>29</b>     | 20<br><b>40</b>   | ns<br>ns             |
| $t_{D1}$              | Delay Time            | test Figure 1                                |                   | 17<br><b>19</b>     | 30<br><b>40</b>   | ns<br>ns             |
| $t_{D2}$              | Delay Time            | test Figure 1                                |                   | 23<br><b>27</b>     | 50<br><b>60</b>   | ns<br>ns             |
| $t_{PW}$              | Pulse Width           | test Figure 1                                | <b>400</b>        |                     |                   | ns                   |
| <b>Power Supply</b>   |                       |                                              |                   |                     |                   |                      |
| $I_S$                 | Power Supply Current  | $V_{INA} = V_{INB} = 3.0\text{V}$            |                   | 1.4<br><b>1.5</b>   | 4.5<br><b>8</b>   | mA<br>mA             |
| $I_S$                 | Power Supply Current  | $V_{INA} = V_{INB} = 0.0\text{V}$            |                   | 0.18<br><b>0.19</b> | 0.4<br><b>0.6</b> | mA<br>mA             |

**Note 1.** Exceeding the absolute maximum rating may damage the device.

**Note 2.** The device is not guaranteed to function outside its operating rating.

**Note 3.** Devices are ESD sensitive. Handling precautions recommended.

## Test Circuits

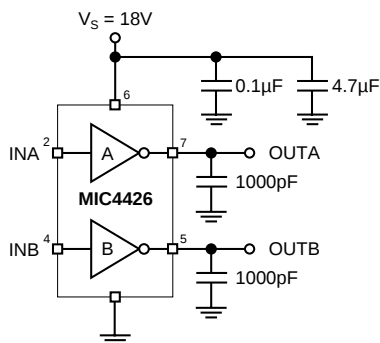


Figure 1a. Inverting Configuration

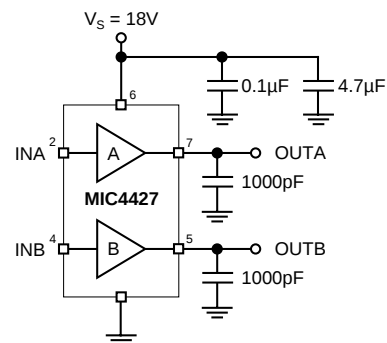


Figure 2a. Noninverting Configuration

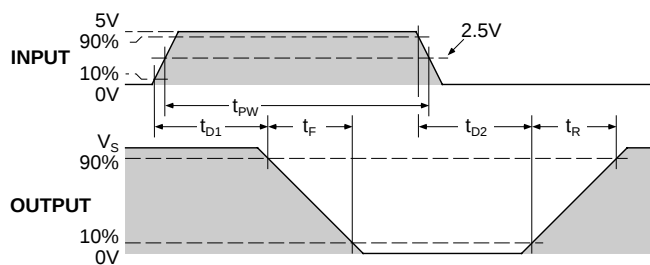


Figure 1b. Inverting Timing

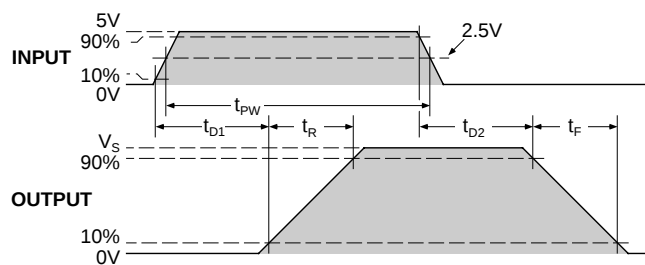
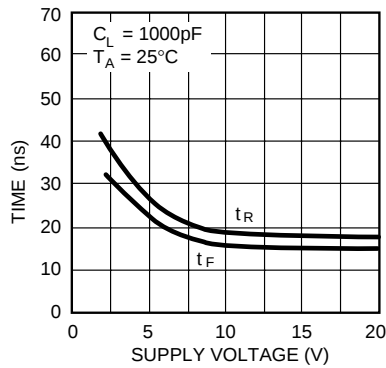


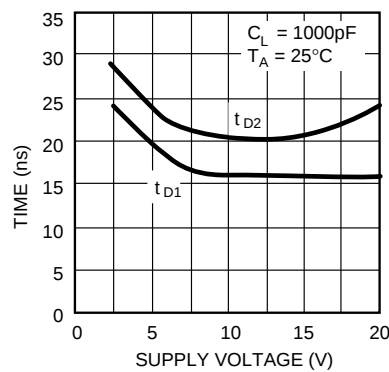
Figure 2b. Noninverting Timing

# Electrical Characteristics

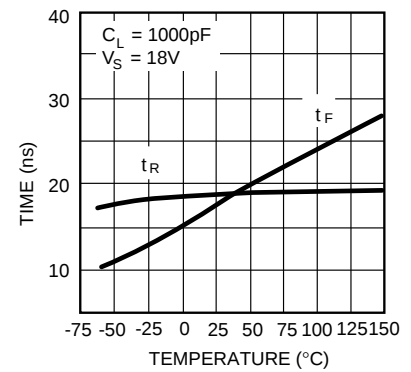
**Rise and Fall Time vs. Supply Voltage**



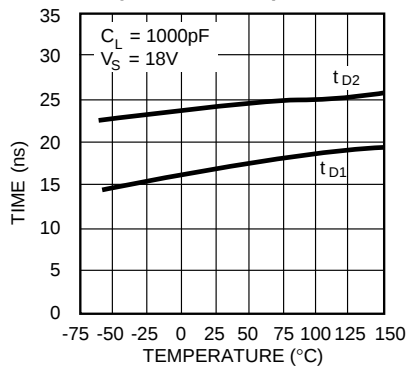
**Delay Time vs. Supply Voltage**



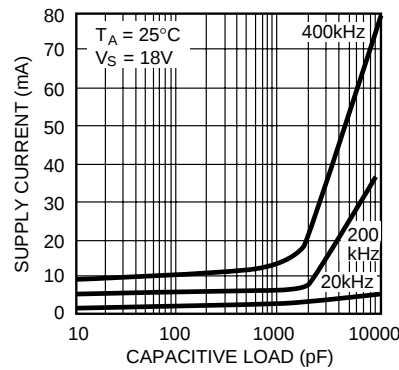
**Rise and Fall Time vs. Temperature**



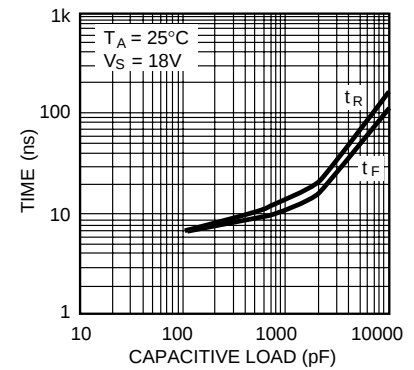
**Delay Time vs. Temperature**



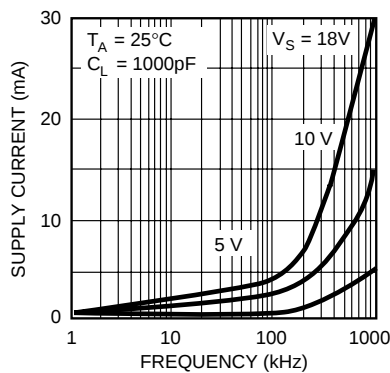
**Supply Current vs. Capacitive Load**



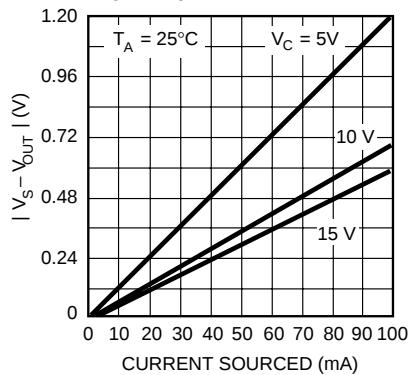
**Rise and Fall Time vs. Capacitive Load**



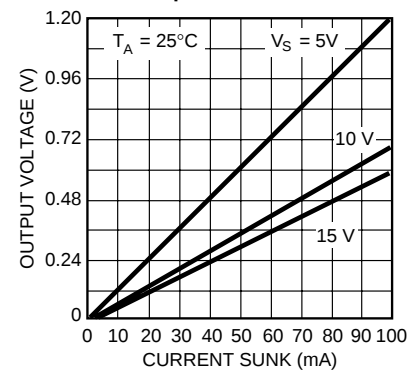
**Supply Current vs. Frequency**



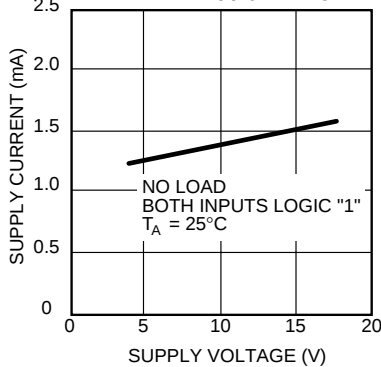
**High Output vs. Current**



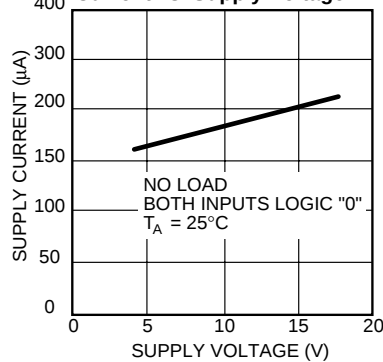
**Low Output vs. Current**



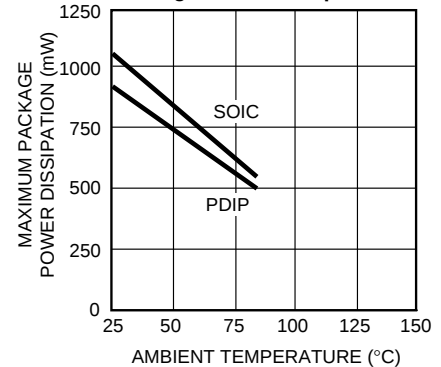
**Quiescent Power Supply Current vs. Supply Voltage**



**Quiescent Power Supply Current vs. Supply Voltage**



**Package Power Dissipation**



## Applications Information

### Supply Bypassing

Large currents are required to charge and discharge large capacitive loads quickly. For example, changing a 1000pF load by 16V in 25ns requires 0.8A from the supply input.

To guarantee low supply impedance over a wide frequency range, parallel capacitors are recommended for power supply bypassing. Low-inductance ceramic MLC capacitors with short lead lengths (< 0.5") should be used. A 1.0μF film capacitor in parallel with one or two 0.1μF ceramic MLC capacitors normally provides adequate bypassing.

### Grounding

When using the inverting drivers in the MIC4426 or MIC4428, individual ground returns for the input and output circuits or a ground plane are recommended for optimum switching speed. The voltage drop that occurs between the driver's ground and the input signal ground, during normal high-current switching, will behave as negative feedback and degrade switching speed.

### Control Input

Unused driver inputs must be connected to logic high (which can be  $V_S$ ) or ground. For the lowest quiescent current (< 500μA), connect unused inputs to ground. A logic-high signal will cause the driver to draw up to 9mA.

The drivers are designed with 100mV of control input hysteresis. This provides clean transitions and minimizes output stage current spikes when changing states. The control input voltage threshold is approximately 1.5V. The control input recognizes 1.5V up to  $V_S$  as a logic high and draws less than 1μA within this range.

The MIC4426/7/8 drives the TL494, SG1526/7, MIC38C42, TSC170 and similar switch-mode power supply integrated circuits.

### Power Dissipation

Power dissipation should be calculated to make sure that the driver is not operated beyond its thermal ratings. Quiescent power dissipation is negligible. A practical value for total power dissipation is the sum of the dissipation caused by the load and the transition power dissipation ( $P_L + P_T$ ).

### Load Dissipation

Power dissipation caused by continuous load current (when driving a resistive load) through the driver's output resistance is:

$$P_L = I_L^2 R_O$$

For capacitive loads, the dissipation in the driver is:

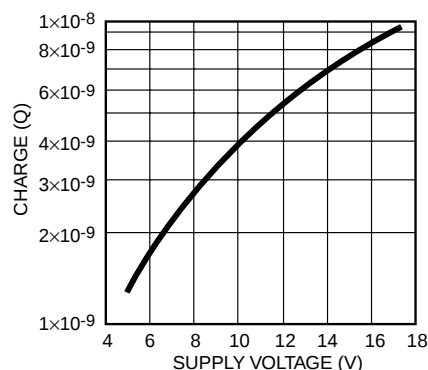
$$P_L = f C_L V_S^2$$

### Transition Dissipation

In applications switching at a high frequency, transition power dissipation can be significant. This occurs during switching transitions when the P-channel and N-channel output FETs are both conducting for the brief moment when one is turning on and the other is turning off.

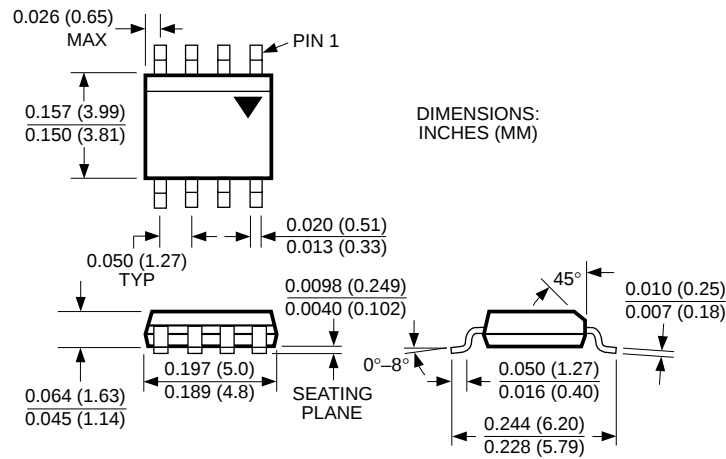
$$P_T = 2 f V_S Q$$

Charge (Q) is read from the following graph:

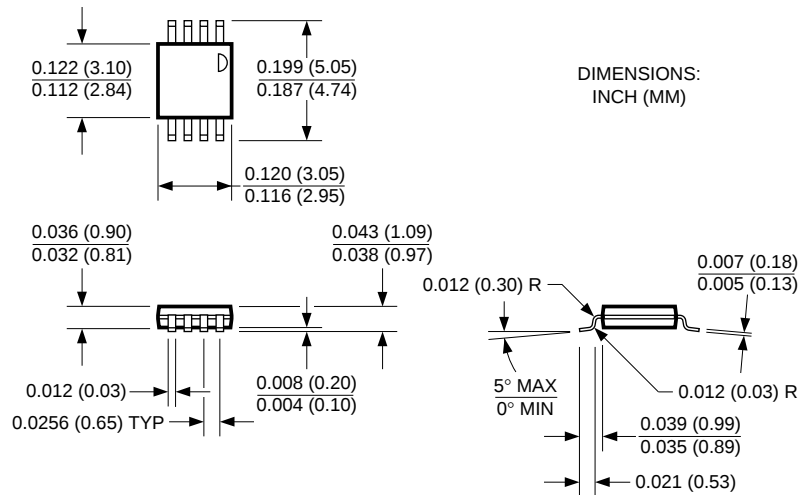


Crossover Energy Loss per Transition

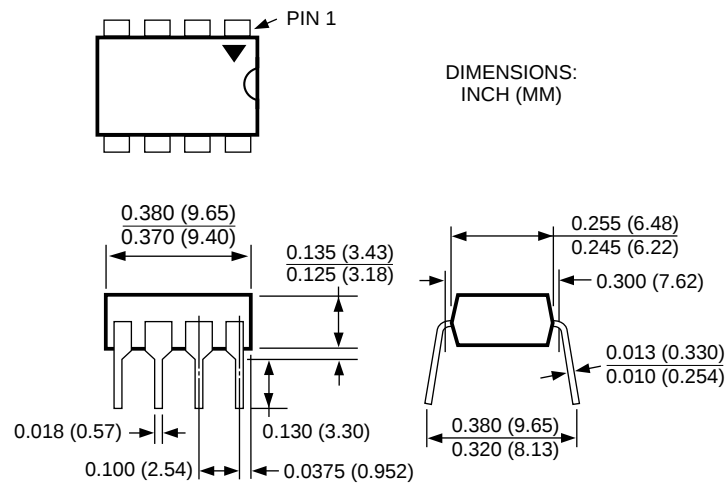
## Package Information



**8-lead SOP (M)**



**8-lead MM8™ MSOP (MM)**



**8-lead Plastic DIP (N)**

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